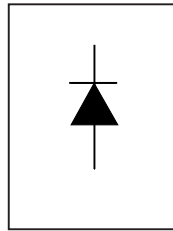


International
IOR Rectifier

QUIETIR Series
 40EPF12PbF

**FAST SOFT RECOVERY
 RECTIFIER DIODE**
 Lead-Free ("PbF" suffix)



$V_F < 1.25V @ 20A$
 $t_{rr} = 95 \text{ ns}$
 $V_{RRM} = 1200V$

Description/ Features

The 40EPF12PbF fast soft recovery **QUIETIR** rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

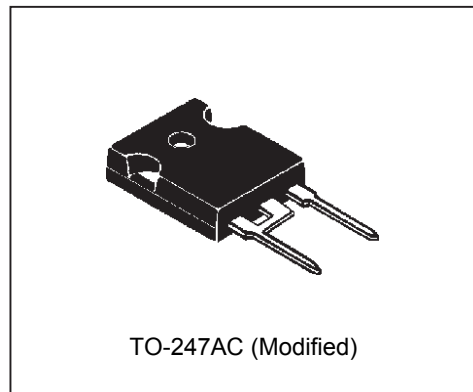
Typical applications are both:

- output rectification and freewheeling in inverters, choppers and converters
- and input rectifications where severe restrictions on conducted EMI should be met.

Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Sinusoidal waveform	40	A
V_{RRM}	1200	V
I_{FSM}	475	A
$V_F @ 20 \text{ A}, T_J = 25^\circ\text{C}$	1.25	V
$t_{rr} @ 1 \text{ A}, -100 \text{ A}/\mu\text{s}$	95	ns
T_J	-40 to 150	$^\circ\text{C}$

Package Outline



Voltage Ratings

Part Number	V_{RRM} , maximum peak reverse voltage V	V_{RSM} , maximum non repetitive peak reverse voltage V	I_{RRM} 150°C mA
40EPF12PbF	1200	1300	10

Absolute Maximum Ratings

Parameters	40EPF..	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	40	A	@ $T_C = 105^\circ\text{C}$, 180° conduction half sine wave
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current	400	A	10ms Sine pulse, rated V_{RRM} applied
	475		10ms Sine pulse, no voltage reapplied
I^2t Max. I^2t for fusing	800	A^2s	10ms Sine pulse, rated V_{RRM} applied
	1131		10ms Sine pulse, no voltage reapplied
I^2vt Max. I^2v/t for fusing	11310	A^2/vs	$t = 0.1$ to 10ms, no voltage reapplied

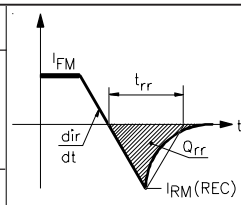
Electrical Specifications

Parameters	40EPF..	Units	Conditions
V_{FM} Max. Forward Voltage Drop	1.4	V	@ 40A, $T_J = 25^\circ\text{C}$
r_t Forward slope resistance	6.82	mΩ	$T_J = 125^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.94	V	
I_{RM} Max. Reverse Leakage Current	0.1	mA	$T_J = 25^\circ\text{C}$
	10		$T_J = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

Recovery Characteristics

Parameters	40EPF..	Units	Conditions
t_{rr} Reverse Recovery Time	450	ns	$I_F @ 10\text{Apk}$ @ 25A/μs @ 25°C
I_{rr} Reverse Recovery Current	6	A	
Q_{rr} Reverse Recovery Charge	1.8	μC	
S Typical Snap Factor	0.5		



Thermal-Mechanical Specifications

Parameters		40EPF..	Units	Conditions
T_J	Max. Junction Temperature Range	-40 to 150	°C	
T_{stg}	Max. Storage Temperature Range	-40 to 150	°C	
R_{thJC}	Max. Thermal Resistance Junction to Case	0.6	°C/W	DC operation
R_{thJA}	Max. Thermal Resistance Junction to Ambient	40	°C/W	
R_{thCS}	Typical Thermal Resistance, Case to Heatsink	0.2	°C/W	Mounting surface , smooth and greased
wt	Approximate Weight	6 (0.21)	g (oz.)	
T	Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)
		Max.	12 (10)	
Case Style		TO-247AC		JEDEC (Modified)
Marking Device		40EPF12		

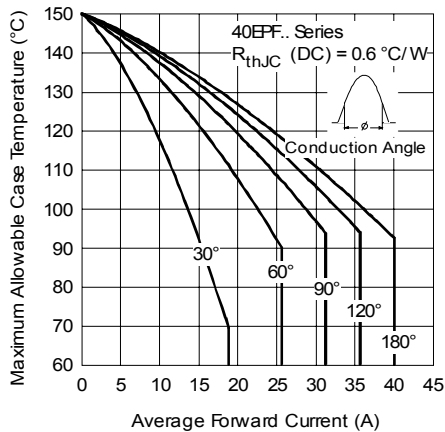


Fig. 1 - Current Rating Characteristics

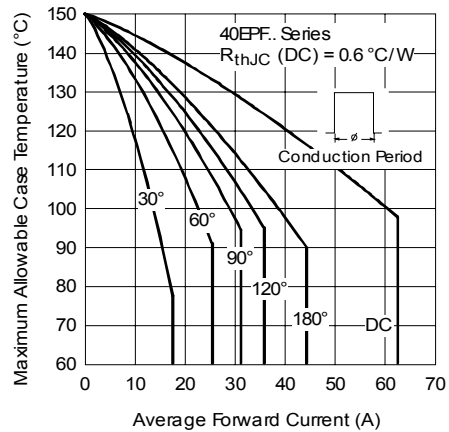


Fig. 2 - Current Rating Characteristics

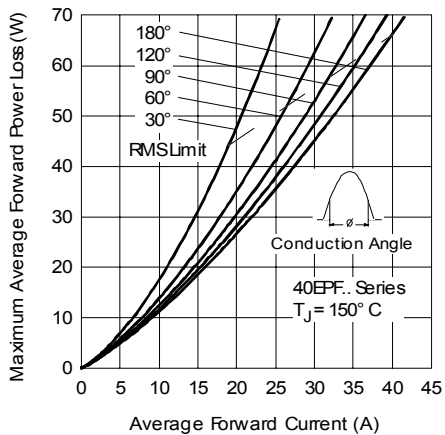


Fig. 3 - Forward Power Loss Characteristics

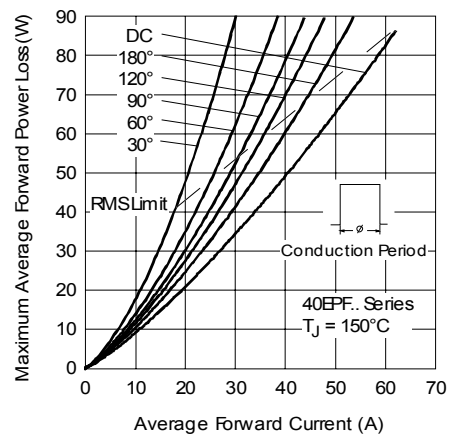


Fig. 4 - Forward Power Loss Characteristics

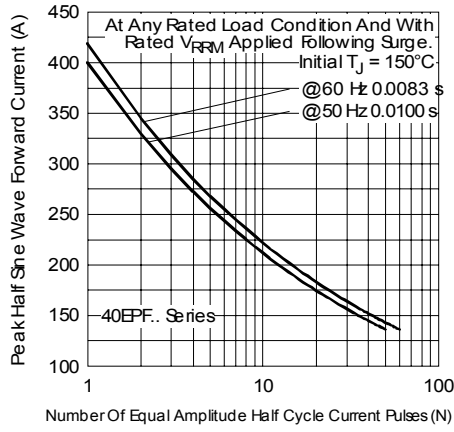


Fig. 5 - Maximum Non-Repetitive Surge Current

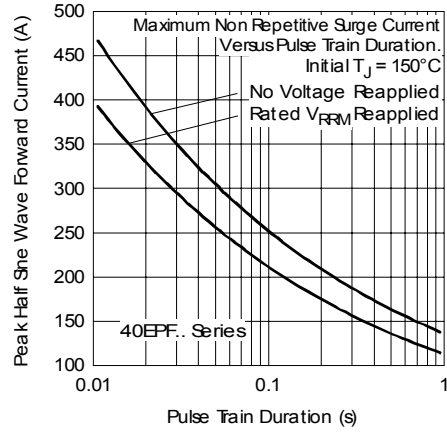


Fig. 6 - Maximum Non-Repetitive Surge Current

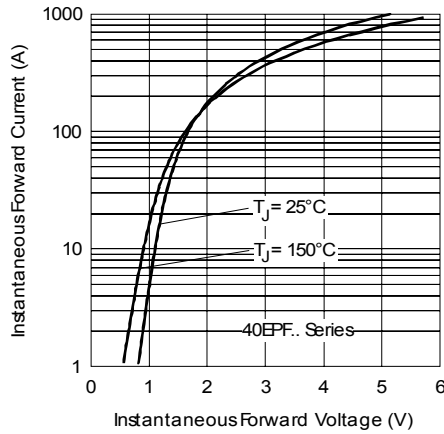


Fig. 7 - Forward Voltage Drop Characteristics

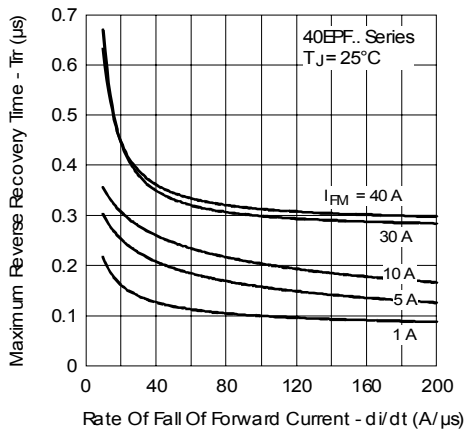


Fig. 8 - Recovery Time Characteristics, $T_J = 25^\circ\text{C}$

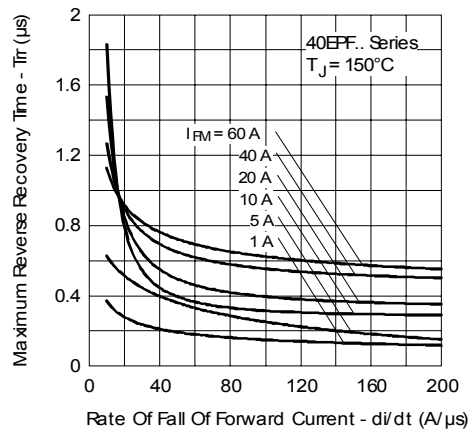


Fig. 9 - Recovery Time Characteristics, $T_J = 150^\circ\text{C}$

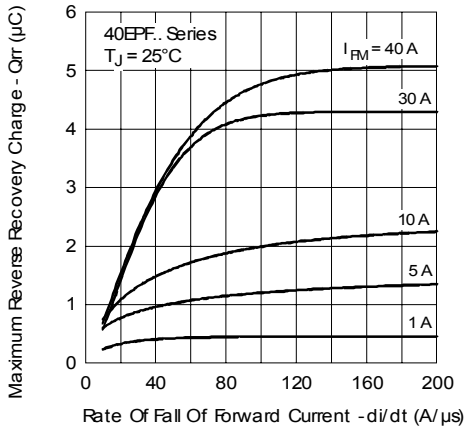


Fig. 10 - Recovery Charge Characteristics, $T_J = 25^\circ\text{C}$

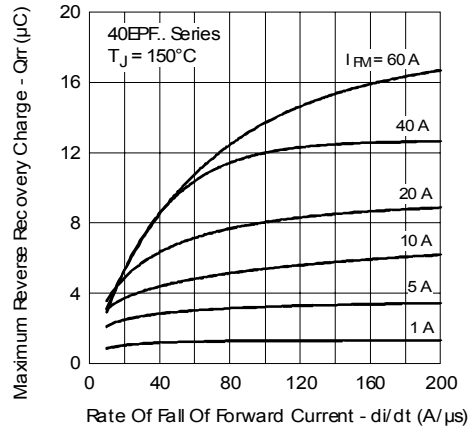


Fig. 11 - Recovery Charge Characteristics, $T_J = 150^\circ\text{C}$

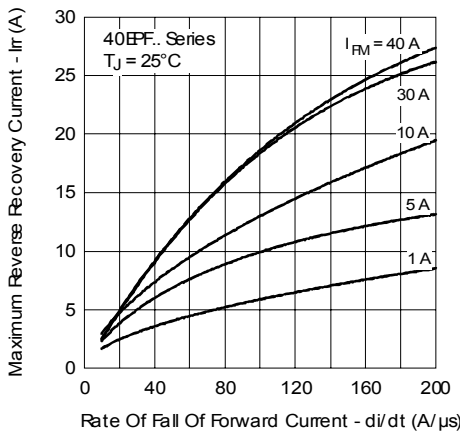


Fig. 12 - Recovery Current Characteristics, $T_J = 25^\circ\text{C}$

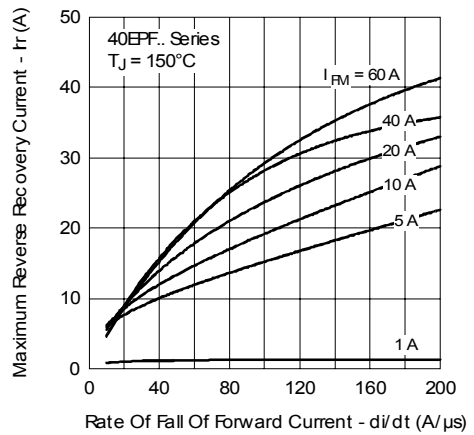


Fig. 13 - Recovery Current Characteristics, $T_J = 150^\circ\text{C}$

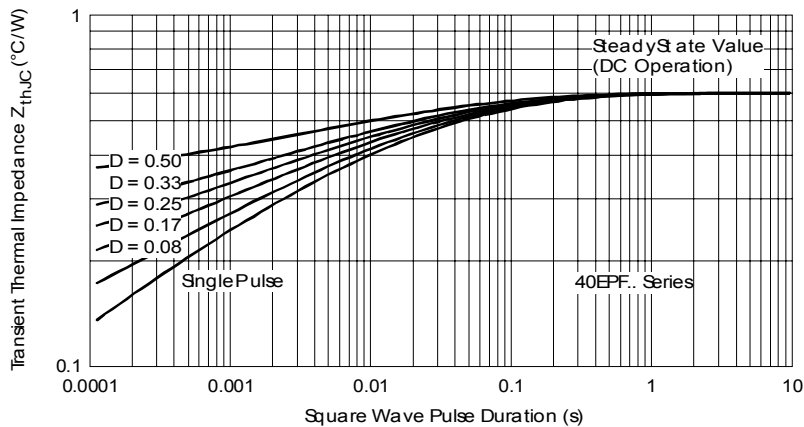
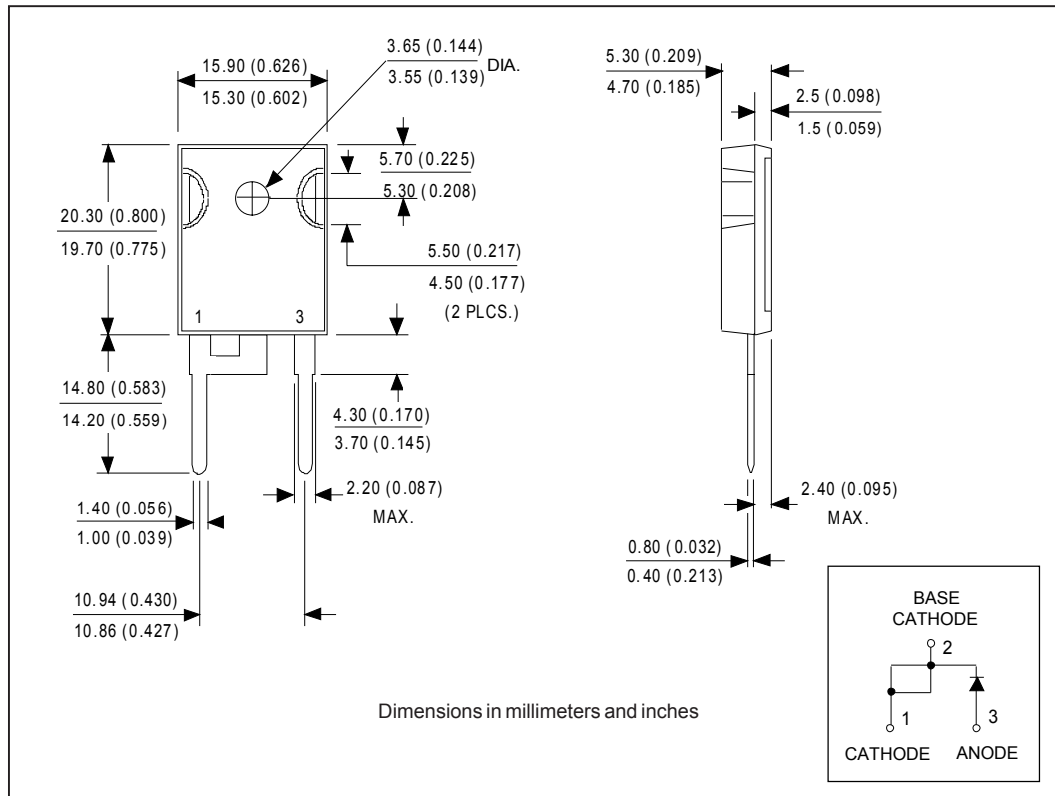
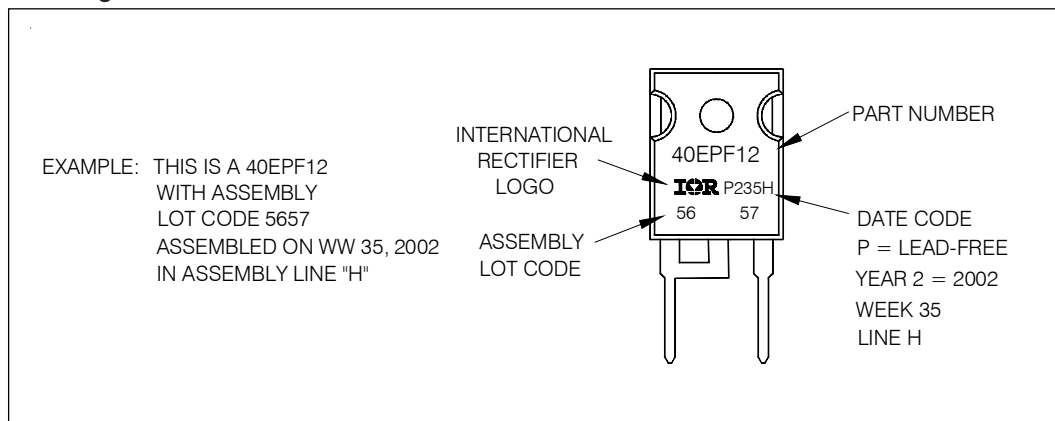


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

Outline Table



Marking Information



Ordering Information Table

Device Code					
40	E	P	F	12	PbF
①	②	③	④	⑤	⑥
1	- Current Rating (40 = 40A)				
2	- Circuit Configuration: E = Single Diode				
3	- Package: P = TO-247AC (Modified)				
4	- Type of Silicon: F = Fast diode				
5	- Voltage rating (12 = 1200V)				
6	- • none = Standard Production • PbF = Lead-Free				

Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level and Lead-Free.
 Qualification Standards can be found on IR's Web site.



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